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October 2013

FDPF2710T

N-Channel PowerTrench[®] MOSFET 250 V, 25 A, 42.5 m Ω

Features

- $R_{DS(on)}$ = 36.3 m Ω (Typ.)@ V_{GS} = 10 V, I_D = 25 A
- · Fast Switching Speed
- · Low Gate Charge
- High Performance Trench Technology for Extremely Low R_{DS(on)}
- · High Power and Current Handling Capability
- RoHS Compliant

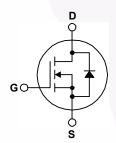
Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advance PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Consumer Appliances
- · Synchronous Rectification





Absolute Maximum Ratings

Symbol		Parameter		FDPF2710T	Unit
V _{DS}	Drain-Source Voltage			250	V
V_{GS}	Gate-Source voltage			± 30	V
I _D	Drain Current	- Continuous ($T_C = 25^{\circ}$) - Continuous ($T_C = 100$)		25 18.8	A A
I _{DM}	Drain Current	- Pulsed	(Note 1)	100	А
E _{AS}	Single Pulsed Avalar	nche Energy	(Note 2)	145	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	4.5	V/ns
P_{D}	Power Dissipation (T _C = 25°C) - Derate above 25°C			62.5 0.5	W W/°C
$T_{J,}T_{STG}$	Operating and Storage Temperature Range			-55 to +150	°C
T _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		pose,	300	°C

Thermal Characteristics

Symbol	Parameter	FDPF2710T	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.0	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDPF2710T	FDPF2710T	TO-220F	Tube	N/A	50 units

Electrical Characteristics $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Off Charac	Off Characteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V$, $I_D = 250\mu A$, $T_J = 25^{\circ}C$	250			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		0.25		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 250V, V_{GS} = 0V$ $V_{DS} = 250V, V_{GS} = 0V, T_{C} = 125^{\circ}C$			10 500	μA μA
I _{GSSF}	Gate-Body Leakage Current, Forward	$V_{GS} = 30V, V_{DS} = 0V$			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -30V$, $V_{DS} = 0V$			-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0	3.9	5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 25A		36.3	42.5	mΩ
9 _{FS}	Forward Transconductance	V _{DS} = 10V, I _D = 25A		63		S
Dynamic C	haracteristics					
C _{iss}	Input Capacitance			5470	7280	pF
C _{oss}	Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz		426	567	pF
C _{rss}	Reverse Transfer Capacitance	- 1 - 1.0ivii iz	\	97	146	pF
Switching	Characteristics		\			
t _{d(on)}	Turn-On Delay Time $V_{DD} = 125V, I_D = 50A$			80	170	ns
t _r	Turn-On Rise Time	$V_{GS} = 10V$, $R_{GEN} = 25\Omega$		252	514	ns
t _{d(off)}	Turn-Off Delay Time			112	234	ns
t _f	Turn-Off Fall Time	(Note 4)		154	318	ns
Q _g	Total Gate Charge	V _{DS} = 125V, I _D = 50A		78	101	nC
Q_{gs}	Gate-Source Charge	V _{GS} = 10V		34		nC
Q_{gd}	Gate-Drain Charge	(Note 4)		18		nC
Drain-Sour	ce Diode Characteristics and Maximun	n Ratings				
I _S Maximum Continuous Drain-Source Diode Forward Current			/		25	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				150	Α
V _{SD}	Drain-Source Diode Forward Voltage $V_{GS} = 0V$, $I_{S} = 25A$		/		1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _S = 50A		163	/	ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =130A/μs		1.3		μС

Notes

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L = 1mH, I_{AS} = 17A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}$ C
- 3. $I_{SD} \leq$ 50A, di/dt \leq 200A/ μ s, $V_{DD} \leq$ BV $_{DSS}$, Starting T_J = 25°C
- 4. Essentially Independent of Operating Temperature Typical Characteristics

Typical Performance Characteristics

Figure 1. On-Region Characteristics

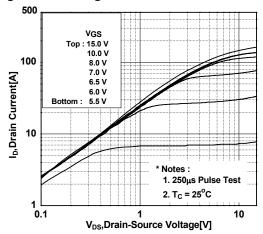


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

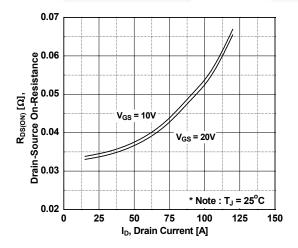


Figure 5. Capacitance Characteristics

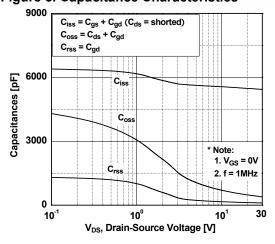


Figure 2. Transfer Characteristics

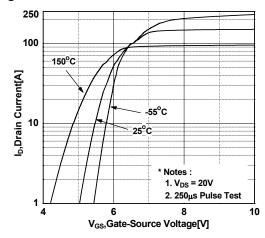


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

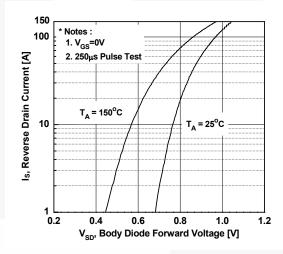
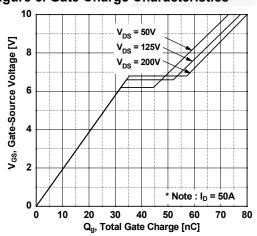


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

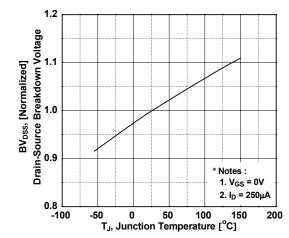


Figure 9. Maximum Safe Operating Area

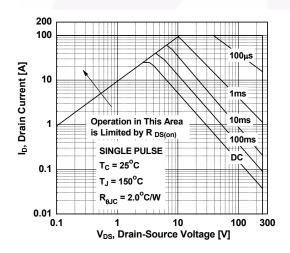


Figure 8. On-Resistance Variation vs. Temperature

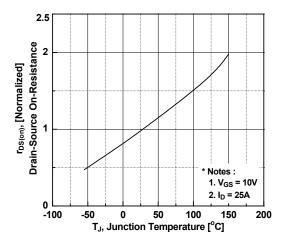


Figure 10. Maximum Drain Current vs. Case Temperature

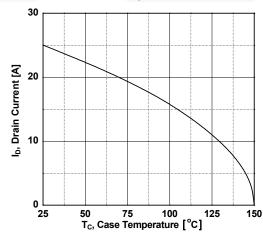


Figure 11. Transient Thermal Response Curve

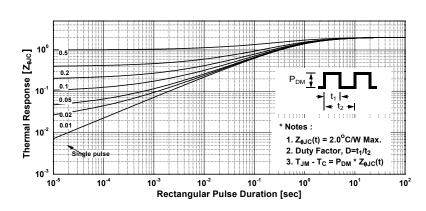


Figure 12. Gate Charge Test Circuit & Waveform

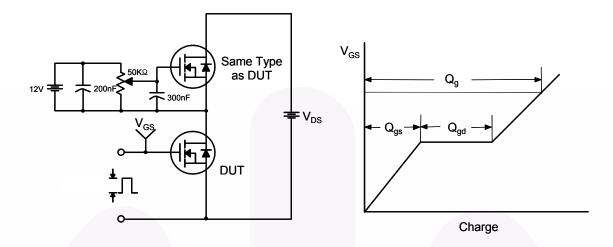


Figure 13. Resistive Switching Test Circuit & Waveforms

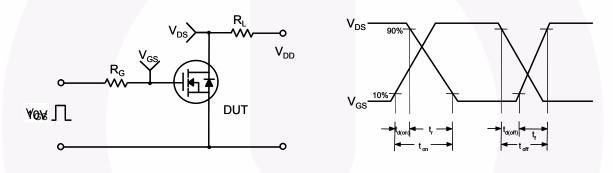


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

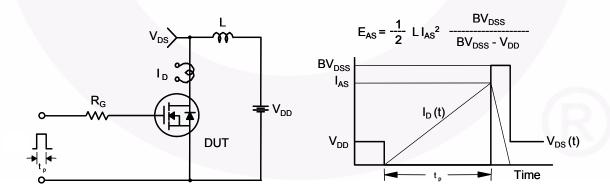
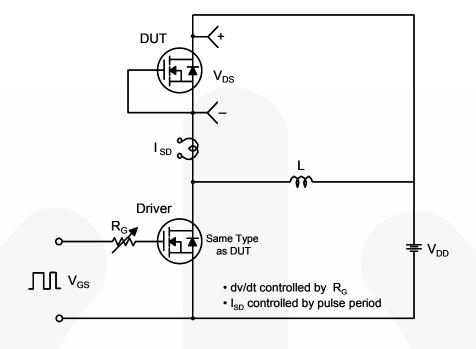
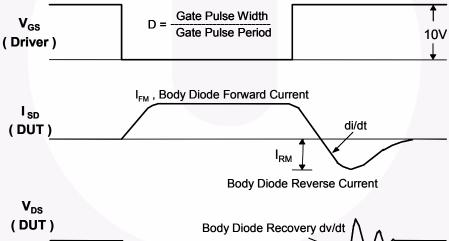


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms





Mechanical Dimensions

TO-220F 3L

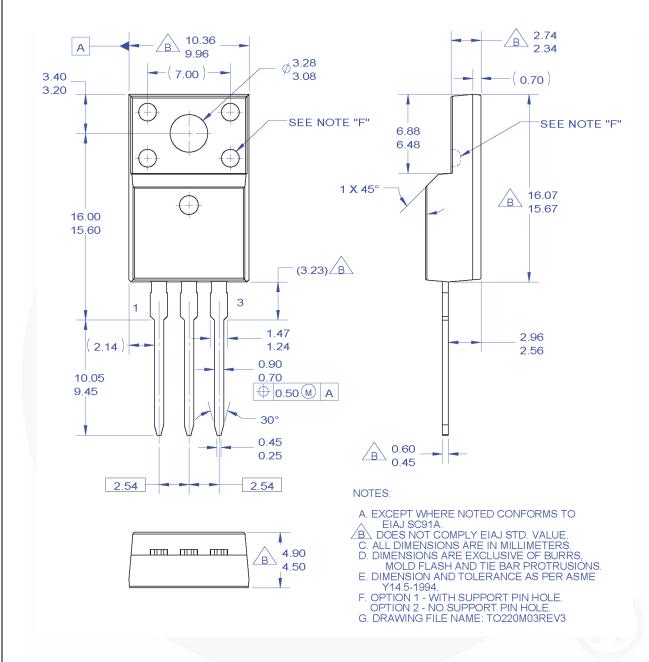


Figure 16. TO220, Molded, 3LD, Full Pack, EIAJ SC91, Straight Lead

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Dimension in Millimeters





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